

# Silicon Diode

## **BYM07-400**

Fast Efficient Rectifier

400V / 0,5A

# DATASHEET

from

[www.web-bcs.com](http://www.web-bcs.com)

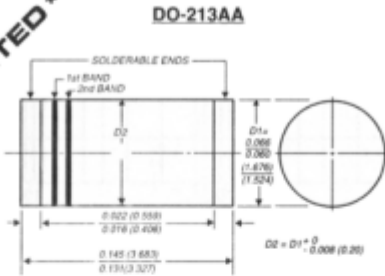
OEM – General Semiconductor

Source: General Semiconductor Databook 1998

# BYM07-50 THRU BYM07-400 EGL34A THRU EGL34G

**SURFACE MOUNT GLASS PASSIVATED JUNCTION FAST EFFICIENT RECTIFIER**  
*Reverse Voltage - 50 to 400 Volts      Forward Current - 0.5 Ampere*

**PATENTED \***



1st band denotes type and polarity  
2nd band denotes voltage type

Dimensions in inches and (millimeters)

\* Glass-plastic encapsulation is covered by

Patent No. 3,996,602 and brazed-lead assembly to Patent No. 3,930,306



## FEATURES

- ◆ Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- ◆ Capable of meeting environmental standards of MIL-S-19500
- ◆ For surface mount applications
- ◆ High temperature metallurgically bonded construction
- ◆ Glass passivated cavity-free junction
- ◆ Fast switching for high efficiency
- ◆ High temperature soldering guaranteed:  
450°C/5 seconds at terminals. Complete device submersible temperature of 260°C for 10 seconds in solder bath



## MECHANICAL DATA

**Case:** JEDEC DO-213AA molded plastic over glass body

**Terminals:** Plated terminals, solderable per MIL-STD-750, Method 2026

**Polarity:** Two bands indicate cathode end -1st band denotes device type and 2nd band denotes repetitive peak reverse voltage rating

**Mounting Position:** Any

**Weight:** 0.0014 ounce, 0.036 gram

## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

	SYMBOLS	BYM07 -50	BYM07 -100	BYM07 -150	BYM07 -200	BYM07 -300	BYM07 -400	UNITS
Fast efficient device: 1st band is Green		EGL34A	EGL34B	EGL34C	EGL34D	EGL34F	EGL34G	
Polarity color bands (2nd Band)		GRAY	RED	PINK	ORANGE	BROWN	YELLOW	
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	50	100	150	200	300	400	Volts
Maximum RMS voltage	V <sub>RMS</sub>	35	70	105	140	210	280	Volts
Maximum DC blocking voltage	V <sub>DC</sub>	50	100	150	200	300	400	Volts
Maximum average forward rectified current at T <sub>J</sub> =75°C	I <sub>(AV)</sub>	0.5						Amp
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I <sub>FSM</sub>	10.0						Amps
Maximum instantaneous forward voltage at 0.5A	V <sub>F</sub>				1.25	1.35		Volts
Maximum DC reverse current at rated DC blocking voltage	I <sub>R</sub>				5.0			μA
					50.0			
Maximum full load reverse current, full cycle average at T <sub>A</sub> =55°C	I <sub>R(AV)</sub>				50.0			μA
Maximum reverse recovery time (NOTE 1)	t <sub>rr</sub>				50.0			ns
Typical junction capacitance (NOTE 2)	C <sub>J</sub>				7.0			pF
Maximum thermal resistance (NOTE 3)	R <sub>θJA</sub>				150.0			°C/W
(NOTE 4)	R <sub>θJT</sub>				70.0			
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	-65 to +175						°C

**NOTES:**

(1) Reverse recovery test conditions: I<sub>F</sub>=0.5A, I<sub>R</sub>=1.0A, I<sub>SM</sub>=0.25A

(2) Measured at 1.0 MHz and applied reverse voltage of 4.0 Volts

(3) Thermal resistance from junction to ambient, 0.24 x 0.24" (6.0 x 6.0mm) copper pads to each terminal

(4) Thermal resistance from junction to terminal, 0.24 x 0.24" (6.0 x 6.0mm) copper pads to each terminal

**RATINGS AND CHARACTERISTIC CURVES BYM07-50 THRU BYM07-400 / EGL34A THRU EGL34G**

